

DATA SHEET

74LVC1G02 Single 2-input NOR gate

Product specification
Supersedes data of 2002 Oct 02

2004 Sep 07

Single 2-input NOR gate

74LVC1G02

FEATURES

- Wide supply voltage range from 1.65 V to 5.5 V
- High noise immunity
- Complies with JEDEC standard:
 - JESD8-7 (1.65 V to 1.95 V)
 - JESD8-5 (2.3 V to 2.7 V)
 - JESD8B/JESD36 (2.7 V to 3.6 V).
- ± 24 mA output drive ($V_{CC} = 3.0$ V)
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Multiple package options
- ESD protection:
 - HBM EIA/JESD22-A114-B exceeds 2000 V
 - MM EIA/JESD22-A115-A exceeds 200 V.
- Specified from -40 °C to $+85$ °C and -40 °C to $+125$ °C.

DESCRIPTION

The 74LVC1G02 is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families.

Input can be driven from either 3.3 V or 5 V devices. These features allow the use of these devices in a mixed 3.3 V and 5 V environment.

Schmitt trigger action at all inputs makes the circuit tolerant for slower input rise and fall time.

This device is fully specified for partial power-down applications using I_{off} . The I_{off} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

The 74LVC1G02 provides the single 2-input NOR function.

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25$ °C; $t_r = t_f \leq 2.5$ ns.

| SYMBOL | PARAMETER | CONDITIONS | TYPICAL | UNIT |
|-------------------|--|---|---------|------|
| t_{PHL}/t_{PLH} | propagation delay inputs A, B to output Y | $V_{CC} = 1.8$ V; $C_L = 30$ pF; $R_L = 1$ k Ω | 3.2 | ns |
| | | $V_{CC} = 2.5$ V; $C_L = 30$ pF; $R_L = 500$ Ω | 2.2 | ns |
| | | $V_{CC} = 2.7$ V; $C_L = 50$ pF; $R_L = 500$ Ω | 2.5 | ns |
| | | $V_{CC} = 3.3$ V; $C_L = 50$ pF; $R_L = 500$ Ω | 2.1 | ns |
| | | $V_{CC} = 5.0$ V; $C_L = 50$ pF; $R_L = 500$ Ω | 1.7 | ns |
| C_I | input capacitance | | 5 | pF |
| C_{PD} | power dissipation capacitance per buffer | $V_{CC} = 3.3$ V; notes 1 and 2 | 14 | pF |

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts;

N = total load switching outputs;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

2. The condition is $V_I = \text{GND to } V_{CC}$.

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FUNCTION TABLE

See note 1.

| INPUT | | OUTPUT |
|-------|---|--------|
| A | B | Y |
| L | L | H |
| L | H | L |
| H | L | L |
| H | H | L |

Note

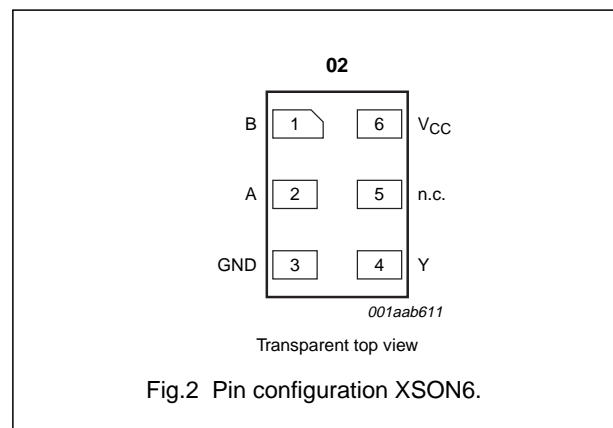
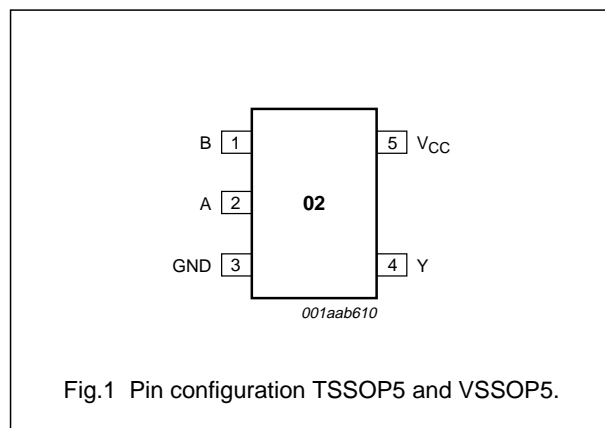
1. H = HIGH voltage level;
L = LOW voltage level.

ORDERING INFORMATION

| TYPE NUMBER | PACKAGE | | | | | |
|-------------|-------------------|------|---------|----------|--------|---------|
| | TEMPERATURE RANGE | PINS | PACKAGE | MATERIAL | CODE | MARKING |
| 74LVC1G02GW | -40 °C to +125 °C | 5 | SC-88A | plastic | SOT353 | VB |
| 74LVC1G02GV | -40 °C to +125 °C | 5 | SC-74A | plastic | SOT753 | V02 |
| 74LVC1G02GM | -40 °C to +125 °C | 5 | XSON6 | plastic | SOT886 | VB |

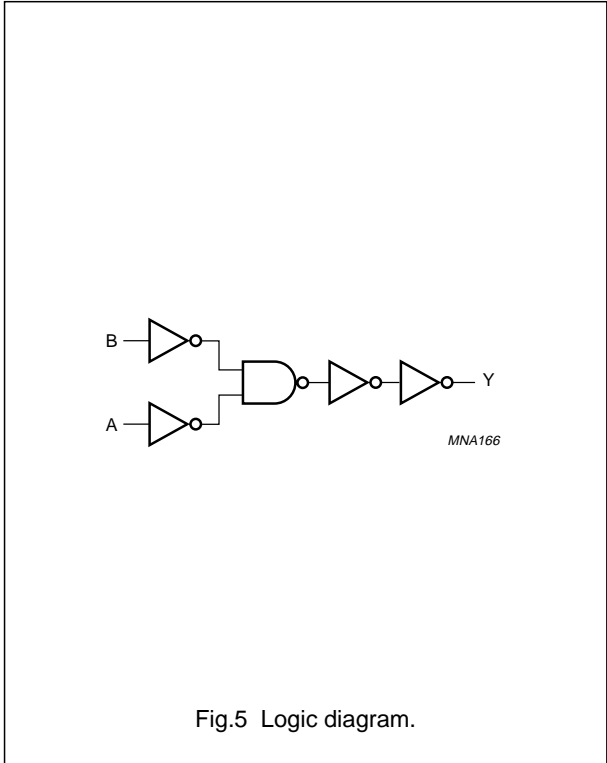
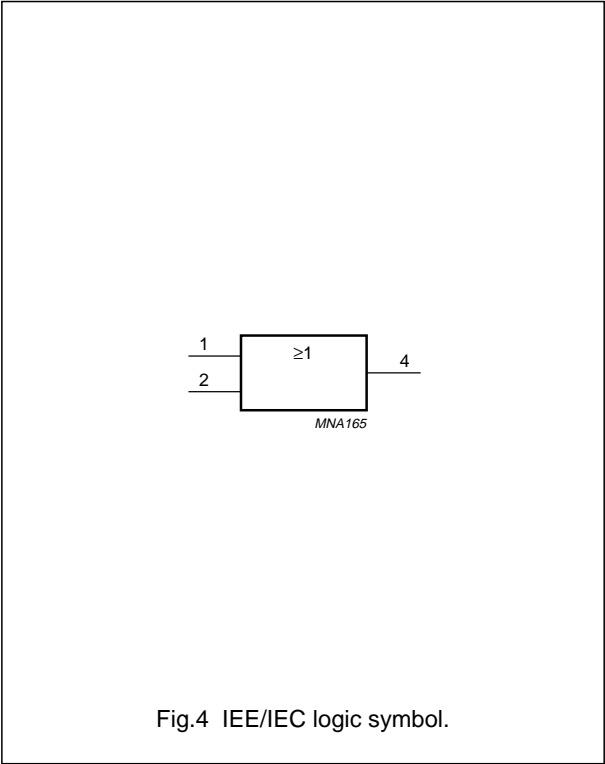
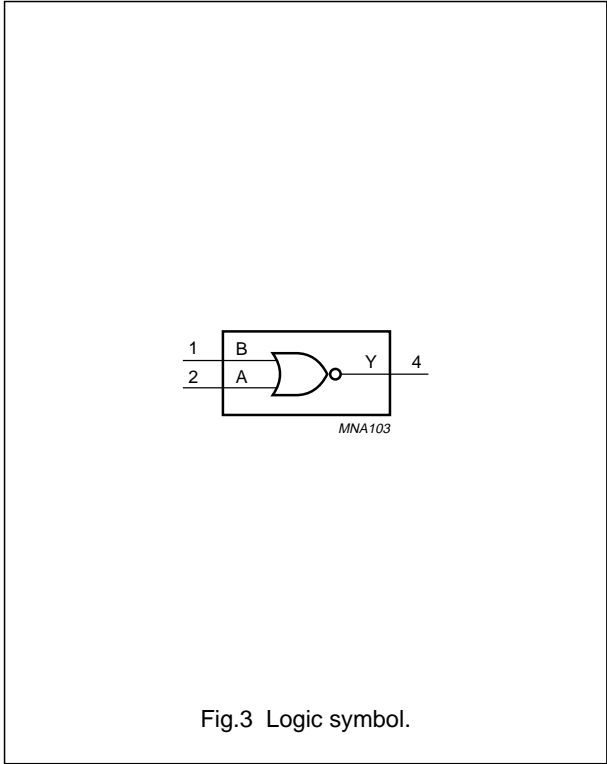
PINNING

| PIN (TSSOP5 AND VSSOP5) | PIN (XSON6) | SYMBOL | DESCRIPTION |
|-------------------------|-------------|-----------------|----------------|
| 1 | 1 | B | data input B |
| 2 | 2 | A | data input A |
| 3 | 3 | GND | ground (0 V) |
| 4 | 4 | Y | data output Y |
| - | 5 | n.c. | not connected |
| 5 | 6 | V _{CC} | supply voltage |



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RECOMMENDED OPERATING CONDITIONS

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------|-------------------------------|---------------------------------|------|----------|------|
| V_{CC} | supply voltage | | 1.65 | 5.5 | V |
| V_I | input voltage | | 0 | 5.5 | V |
| V_O | output voltage | active mode | 0 | V_{CC} | V |
| | | $V_{CC} = 0$ V; Power-down mode | 0 | 5.5 | V |
| T_{amb} | operating ambient temperature | | -40 | +125 | °C |
| t_r, t_f | input rise and fall times | $V_{CC} = 1.65$ V to 2.7 V | 0 | 20 | ns/V |
| | | $V_{CC} = 2.7$ V to 5.5 V | 0 | 10 | ns/V |

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|-------------------|--------------------------------|--------------------------------|------|----------------|------|
| V_{CC} | supply voltage | | -0.5 | +6.5 | V |
| I_{IK} | input diode current | $V_I < 0$ V | - | -50 | mA |
| V_I | input voltage | note 1 | -0.5 | +6.5 | V |
| I_{OK} | output diode current | $V_O > V_{CC}$ or $V_O < 0$ V | - | ± 50 | mA |
| V_O | output voltage | active mode; notes 1 and 2 | -0.5 | $V_{CC} + 0.5$ | V |
| | | Power-down mode; notes 1 and 2 | -0.5 | +6.5 | V |
| I_O | output source and sink current | $V_O = 0$ V to V_{CC} | - | ± 50 | mA |
| I_{CC}, I_{GND} | V_{CC} or GND current | | - | ± 100 | mA |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| P_D | power dissipation | $T_{amb} = -40$ °C to +125 °C | - | 250 | mW |

Notes

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
2. When $V_{CC} = 0$ V (Power-down mode), the output voltage can be 5.5 V in normal operation.

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DC CHARACTERISTICS

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| SYMBOL | PARAMETER | TEST CONDITIONS | | MIN. | TYP. ⁽¹⁾ | MAX. | UNIT |
|---|---|---|---------------------|------------------------|---------------------|------------------------|------|
| | | OTHER | V _{CC} (V) | | | | |
| T_{amb} = -40 °C to +85 °C | | | | | | | |
| V _{IH} | HIGH-level input voltage | | 1.65 to 1.95 | 0.65 × V _{CC} | – | – | V |
| | | | 2.3 to 2.7 | 1.7 | – | – | V |
| | | | 2.7 to 3.6 | 2.0 | – | – | V |
| | | | 4.5 to 5.5 | 0.7 × V _{CC} | – | – | V |
| V _{IL} | LOW-level input voltage | | 1.65 to 1.95 | – | – | 0.35 × V _{CC} | V |
| | | | 2.3 to 2.7 | – | – | 0.7 | V |
| | | | 2.7 to 3.6 | – | – | 0.8 | V |
| | | | 4.5 to 5.5 | – | – | 0.3 × V _{CC} | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | 1.65 to 5.5 | – | – | 0.1 | V |
| | | I _O = 100 μA | 1.65 | – | – | 0.45 | V |
| | | I _O = 4 mA | 2.3 | – | – | 0.3 | V |
| | | I _O = 8 mA | 2.7 | – | – | 0.4 | V |
| | | I _O = 12 mA | 3.0 | – | – | 0.55 | V |
| | | I _O = 24 mA | 4.5 | – | – | 0.55 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | 1.65 to 5.5 | V _{CC} – 0.1 | – | – | V |
| | | I _O = –100 μA | 1.65 | 1.2 | – | – | V |
| | | I _O = –4 mA | 2.3 | 1.9 | – | – | V |
| | | I _O = –8 mA | 2.7 | 2.2 | – | – | V |
| | | I _O = –12 mA | 3.0 | 2.3 | – | – | V |
| | | I _O = –24 mA | 4.5 | 3.8 | – | – | V |
| I _{LI} | input leakage current | V _I = 5.5 V or GND | 5.5 | – | ±0.1 | ±5 | μA |
| I _{off} | power OFF leakage current | V _I or V _O = 5.5 V | 0 | – | ±0.1 | ±10 | μA |
| I _{CC} | quiescent supply current | V _I = V _{CC} or GND; I _O = 0 A | 5.5 | – | 0.1 | 10 | μA |
| ΔI _{CC} | additional quiescent supply current per pin | V _I = V _{CC} – 0.6 V; I _O = 0 A | 2.3 to 5.5 | – | 5 | 500 | μA |

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| SYMBOL | PARAMETER | TEST CONDITIONS | | MIN. | TYP. ⁽¹⁾ | MAX. | UNIT |
|--|---|---|---------------------|------------------------|---------------------|------------------------|------|
| | | OTHER | V _{CC} (V) | | | | |
| T_{amb} = -40 °C to +125 °C | | | | | | | |
| V _{IH} | HIGH-level input voltage | | 1.65 to 1.95 | 0.65 × V _{CC} | – | – | V |
| | | | 2.3 to 2.7 | 1.7 | – | – | V |
| | | | 2.7 to 3.6 | 2.0 | – | – | V |
| | | | 4.5 to 5.5 | 0.7 × V _{CC} | – | – | V |
| V _{IL} | LOW-level input voltage | | 1.65 to 1.95 | – | – | 0.35 × V _{CC} | V |
| | | | 2.3 to 2.7 | – | – | 0.7 | V |
| | | | 2.7 to 3.6 | – | – | 0.8 | V |
| | | | 4.5 to 5.5 | – | – | 0.3 × V _{CC} | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | 1.65 to 5.5 | – | – | 0.1 | V |
| | | I _O = 100 μA | 1.65 | – | – | 0.70 | V |
| | | I _O = 4 mA | 2.3 | – | – | 0.45 | V |
| | | I _O = 8 mA | 2.7 | – | – | 0.60 | V |
| | | I _O = 12 mA | 3.0 | – | – | 0.80 | V |
| | | I _O = 24 mA | 4.5 | – | – | 0.80 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | 1.65 to 5.5 | V _{CC} – 0.1 | – | – | V |
| | | I _O = –100 μA | 1.65 | 0.95 | – | – | V |
| | | I _O = –4 mA | 2.3 | 1.7 | – | – | V |
| | | I _O = –8 mA | 2.7 | 1.9 | – | – | V |
| | | I _O = –12 mA | 3.0 | 2.0 | – | – | V |
| | | I _O = –24 mA | 4.5 | 3.4 | – | – | V |
| I _{LI} | input leakage current | V _I = 5.5 V or GND | 5.5 | – | ±0.1 | ±100 | μA |
| I _{off} | power OFF leakage current | V _I or V _O = 5.5 V | 0 | – | ±0.1 | ±200 | μA |
| I _{CC} | quiescent supply current | V _I = V _{CC} or GND; I _O = 0 A | 5.5 | – | 0.1 | 200 | μA |
| ΔI _{CC} | additional quiescent supply current per pin | V _I = V _{CC} – 0.6 V; I _O = 0 A | 2.3 to 5.5 | – | 5 | 5000 | μA |

Note

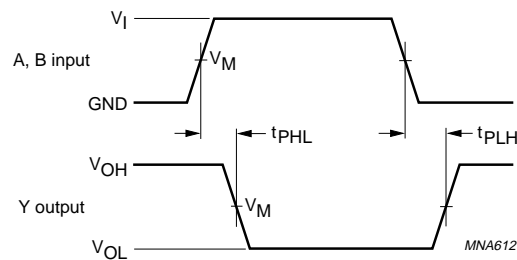
1. All typical values are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

Single 2-input NOR gate

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AC CHARACTERISTICSGND = 0 V; $t_r = t_f \leq 2.0$ ns.

| SYMBOL | PARAMETER | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNIT |
|--|--------------------------------|------------------|--------------|------|------|------|------|
| | | WAVEFORMS | V_{CC} (V) | | | | |
| $T_{amb} = -40$ °C to $+85$ °C | | | | | | | |
| t_{PHL}/t_{PLH} | propagation delay A, B to Y | see Figs 6 and 7 | 1.65 to 1.95 | 1.0 | 3.2 | 8.0 | ns |
| | | | 2.3 to 2.7 | 0.5 | 2.2 | 5.5 | ns |
| | | | 2.7 | 0.5 | 2.5 | 5.5 | ns |
| | | | 3.0 to 3.6 | 0.5 | 2.1 | 4.5 | ns |
| | | | 4.5 to 5.5 | 0.5 | 1.7 | 4.0 | ns |
| $T_{amb} = -40$ °C to $+125$ °C | | | | | | | |
| t_{PHL}/t_{PLH} | propagation delay A, B to Y | see Figs 6 and 7 | 1.65 to 1.95 | 1.0 | – | 10.5 | ns |
| | | | 2.3 to 2.7 | 0.5 | – | 7.0 | ns |
| | | | 2.7 | 0.5 | – | 7.0 | ns |
| | | | 3.0 to 3.6 | 0.5 | – | 6.0 | ns |
| | | | 4.5 to 5.5 | 0.5 | – | 5.5 | ns |

AC WAVEFORMS

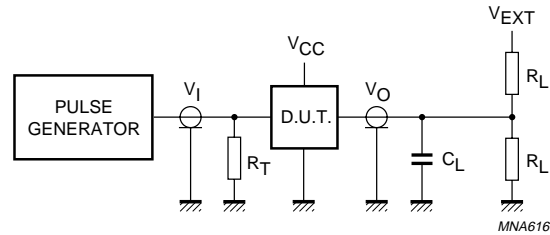
| V_{CC} | V_M | INPUT | |
|------------------|---------------------|----------|---------------|
| | | V_I | $t_r = t_f$ |
| 1.65 V to 1.95 V | $0.5 \times V_{CC}$ | V_{CC} | ≤ 2.0 ns |
| 2.3 V to 2.7 V | $0.5 \times V_{CC}$ | V_{CC} | ≤ 2.0 ns |
| 2.7 V | 1.5 V | 2.7 V | ≤ 2.5 ns |
| 3.0 V to 3.6 V | 1.5 V | 2.7 V | ≤ 2.5 ns |
| 4.5 V to 5.5 V | $0.5 \times V_{CC}$ | V_{CC} | ≤ 2.5 ns |

 V_{OL} and V_{OH} are typical output voltage drop that occur with the output load.

Fig.6 Input A, B to output Y propagation delay times.

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| V _{CC} | V _I | C _L | R _L | V _{EXT} | | |
|------------------|-----------------|----------------|----------------|------------------------------------|------------------------------------|------------------------------------|
| | | | | t _{PLH} /t _{PHL} | t _{PZH} /t _{PHZ} | t _{PZL} /t _{PLZ} |
| 1.65 V to 1.95 V | V _{CC} | 30 pF | 1 kΩ | open | GND | 2 × V _{CC} |
| 2.3 V to 2.7 V | V _{CC} | 30 pF | 500 Ω | open | GND | 2 × V _{CC} |
| 2.7 V | 2.7 V | 50 pF | 500 Ω | open | GND | 6 V |
| 3.0 V to 3.6 V | 2.7 V | 50 pF | 500 Ω | open | GND | 6 V |
| 4.5 V to 5.5 V | V _{CC} | 50 pF | 500 Ω | open | GND | 2 × V _{CC} |

Definitions for test circuit:

R_L = Load resistor.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

Fig.7 Load circuitry for switching times.

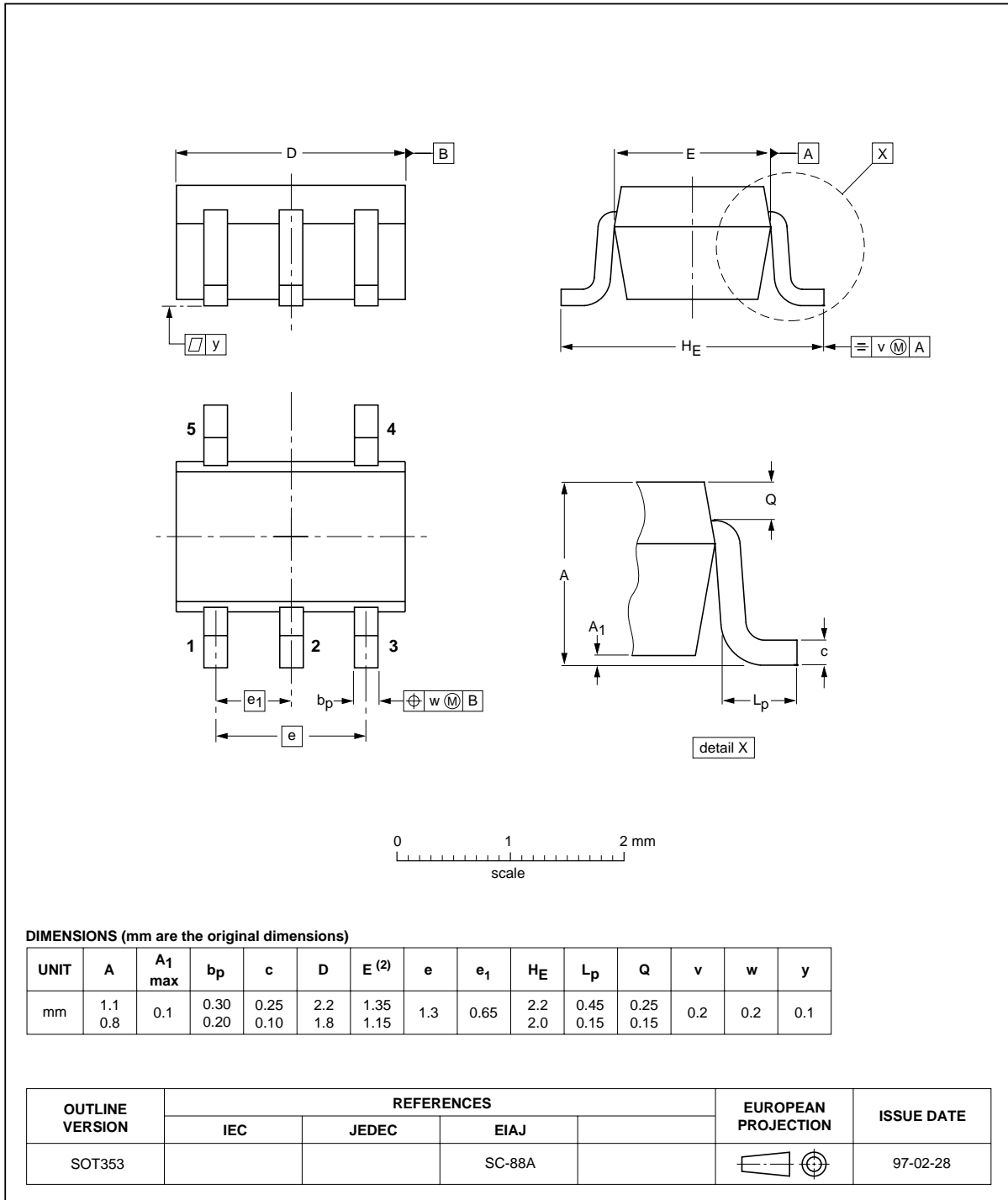
Single 2-input NOR gate

74LVC1G02

PACKAGE OUTLINES

Plastic surface mounted package; 5 leads

SOT353

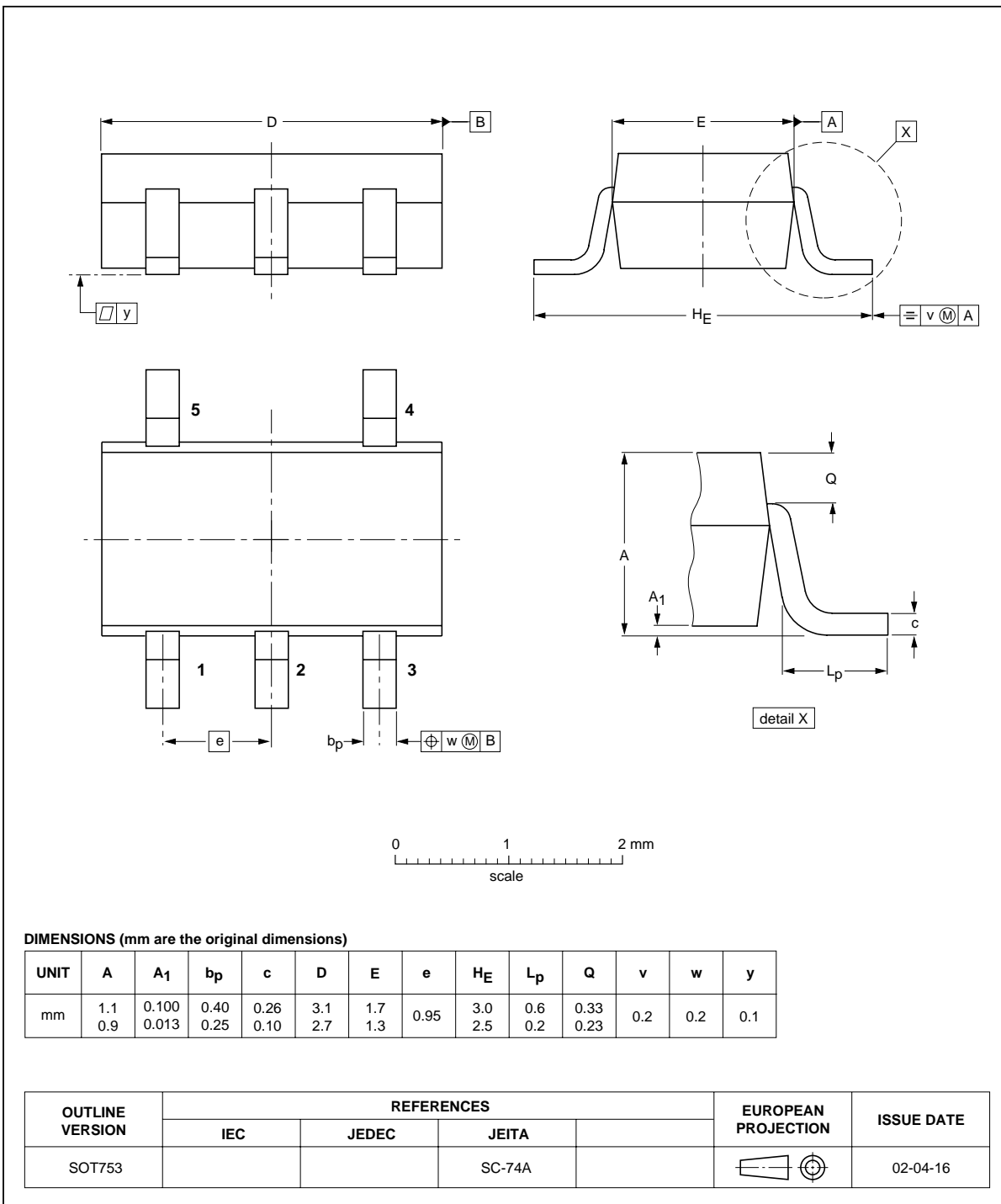


Single 2-input NOR gate

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Plastic surface mounted package; 5 leads

SOT753

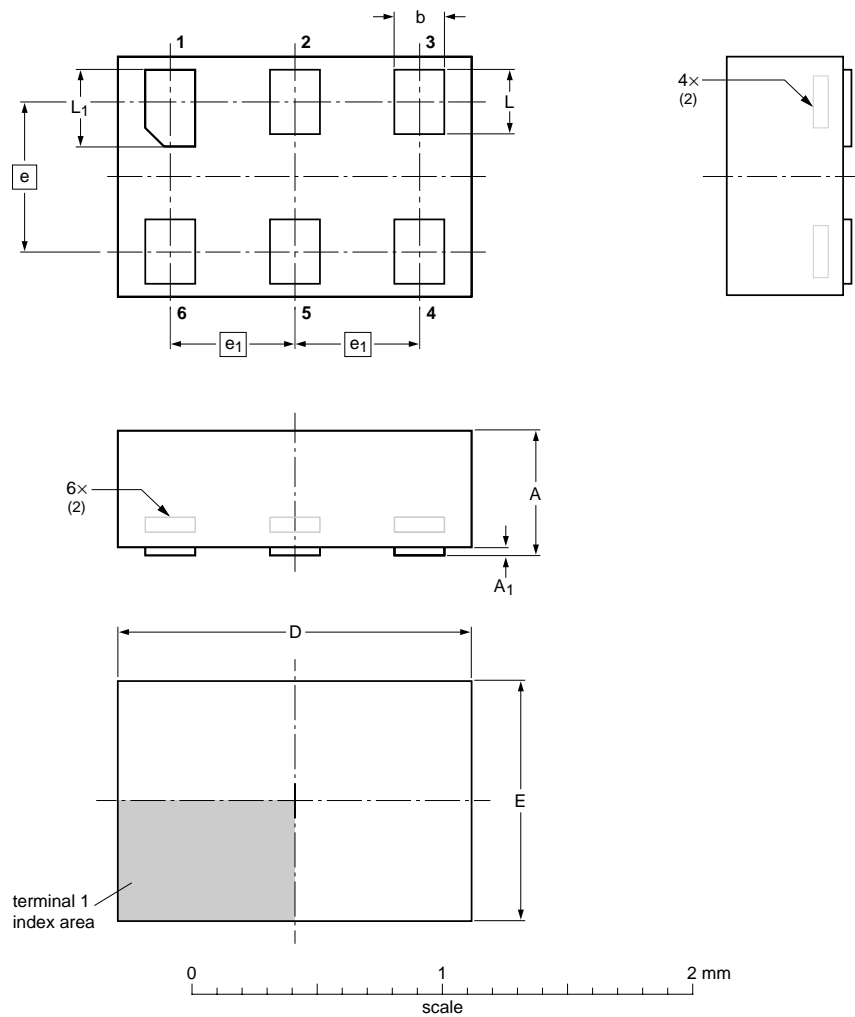


Single 2-input NOR gate

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XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm

SOT886



DIMENSIONS (mm are the original dimensions)

| UNIT | A ⁽¹⁾ max | A ₁ max | b | D | E | e | e ₁ | L | L ₁ |
|------|-------------------------|-----------------------|--------------|------------|--------------|-----|----------------|--------------|----------------|
| mm | 0.5 | 0.04 | 0.25 0.17 | 1.5 1.4 | 1.05 0.95 | 0.6 | 0.5 | 0.35 0.27 | 0.40 0.32 |

Notes

- 1. Including plating thickness.
- 2. Can be visible in some manufacturing processes.

| OUTLINE VERSION | REFERENCES | | | | EUROPEAN PROJECTION | ISSUE DATE |
|--------------------|------------|--------|-------|--|------------------------|-----------------------|
| | IEC | JEDEC | JEITA | | | |
| SOT886 | | MO-252 | | | | -04-07-15 04-07-22 |

Single 2-input NOR gate

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DATA SHEET STATUS

| LEVEL | DATA SHEET STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾⁽³⁾ | DEFINITION |
|-------|----------------------------------|----------------------------------|--|
| I | Objective data | Development | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice. |
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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device.

These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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